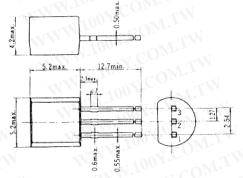


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SILICON PNP EPITAXIAL

HIGH FREQUNCY AMPLIFIER HIGH SPEED SWITCHING



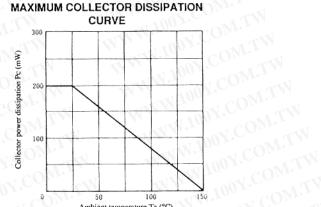


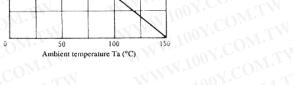
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(JEDEC TO-92)

■ ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

Symbol	2SA781(K)	Unit
Vсво	-20	00v
VCEO	-15	v
VEBO	-4v	v
Ic	-200	mA
Pc	200	mW
Tj	150	°C
Tsig	-55 to +150	°C
	VCBO VCEO VEBO IC PC Tj	VCBO -20 VCEO -15 VEBO -4 IC -200 PC 200 Tj 150





■ ELECTRICAL CHARACTERISTICS (Ta=25°C)

ELECTRICAL CHARACTERISTIC	S (Ta=25°C)	N WWW.100 COM	50 100 1 Ambient temperature Ta (°C)			
Item	Symbol	Test Condition	min.	typ.	max.	Unit
Collector to base breakdown voltage	V(BR)CBO	$Ic = -10\mu A$, $Ie = 0$	-20	-		v
Collector to emitter breakdown voltage	V(BR)CEO	Ic = −10mA, RBE = ∞	-15	-	-	v
Emitter to base breakdown voltage	V(BR)EBO	$IE = -100\mu A$, $IC = 0$	-4	1.7		v
Collector cutoff current	Ісво	$V_{CB} = -16V, IE = 0$	1	14	-0.2	μΑ
Emitter cutoff current	Іево	$V_{EB} = -2V, IC = 0$	N.C.	-	-0.2	μΑ
DC current transfer ratio	hfe	$V_{CE} = -0.5V$, $I_{C} = -30mA$	20	027.	200	
Base to emitter saturation voltage	VBE(sat)	Ic = -30mA, $IB = -1mA$	00 -		-1.0	v
Collector to emitter saturation voltage	VCE(sat)	Ic = -30mA, $IB = -1mA$	_		-0.5	v
Gain bandwidth product	fr	$V_{CE} = -1V$, IC = $-30mA$		550		MHz
Turn on time	ton	$V_{CC} = -5V$, $I_{B1} = -2mA$ $I_{C} = -30mA$, $I_{B2} = 0$		-	70	ns
Turn off time	toff	$V_{CC} = -5V$, $I_{B1} = -2.7mA$ $I_{C} = -30mA$, $I_{B2} = 0$			120	μs



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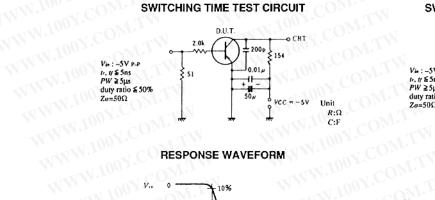
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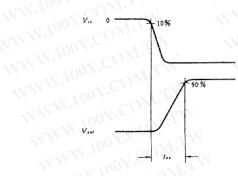
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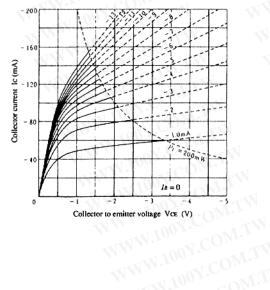


WWW.100Y.CC **RESPONSE WAVEFORM**

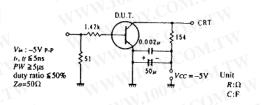


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TYPICAL OUTPUT CHARACTERISTICS (1)

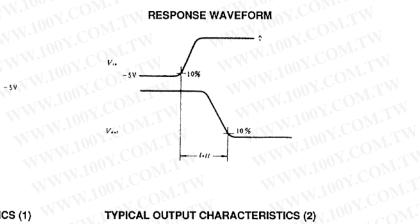


SWITCHING TIME TEST CIRCUIT

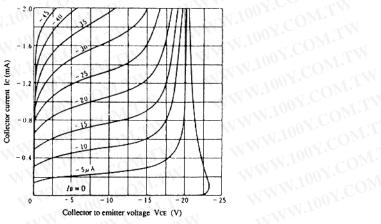


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RESPONSE WAVEFORM



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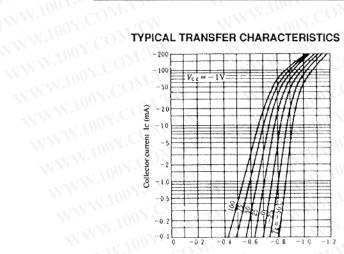


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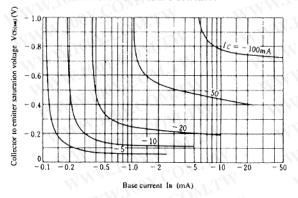
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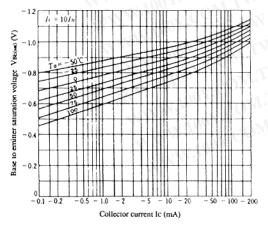


Base to emitter voltage VBE (V)

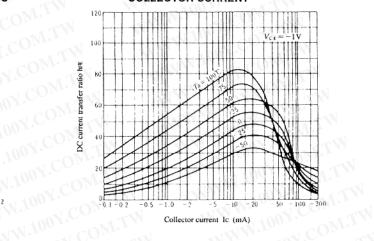




BASE TO EMITTER SATURATION VOLTAGE VS. COLLECTOR CURRENT

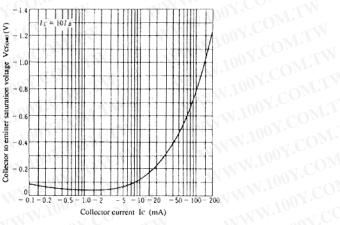


DC CURRENT TRANSFER RATIO VS. COLLECTOR CURRENT

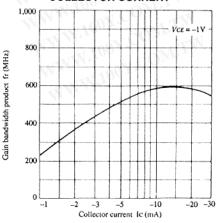


Collector current Ic (mA)

COLLECTOR TO EMITTER SATURATION VOLTAGE VS COLLECTOR CURRENT



GAIN BANDWIDTH PRODUCT VS. COLLECTOR CURRENT



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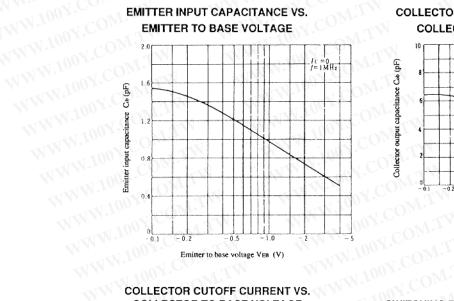
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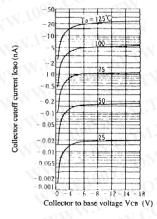
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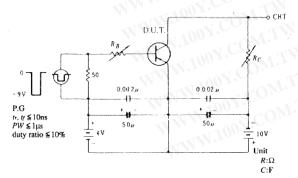
2SA781(K)



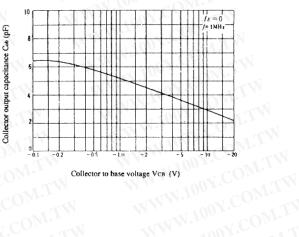
COLLECTOR CUTOFF CURRENT VS. COLLECTOR TO BASE VOLTAGE



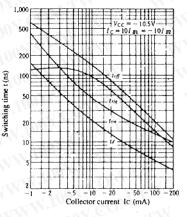
SWITCHING TIME TEST CIRCUIT



COLLECTOR OUTPUT CAPACITANCE VS. COLLECTOR TO BASE VOLTAGE



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RESPONSE WAVEFORM

